

300 mA, Low Voltage, Low Quiescent Current LDO Regulator

Features

- · 300 mA Output Current Capability
- Input Operating Voltage Range: 2.1V to 6.0V
- Adjustable Output Voltage Range: 0.8V to 5.0V (MCP1824 only)
- · Standard Fixed Output Voltages:
 - 0.8V, 1.2V, 1.8V, 2.5V, 3.0V, 3.3V, 5.0V
- Other Fixed Output Voltage Options Available Upon Request
- · Low Dropout Voltage: 200 mV Typical at 300 mA
- Typical Output Voltage Tolerance: 0.4%
- Stable with 1.0 µF Ceramic Output Capacitor
- · Fast Response to Load Transients
- Low Supply Current: 120 μA (typical)
- Low Shutdown Supply Current: 0.1 µA (typical) (MCP1824 only)
- Fixed Delay on Power Good Output (MCP1824 only)
- Short Circuit Current Limiting and Overtemperature Protection
- 5-Lead Plastic SOT-223, SOT-23 Package Options (MCP1824)
- 3-Lead Plastic SOT-223 Package Option (MCP1824S)

Applications

- · High-Speed Driver Chipset Power
- · Networking Backplane Cards
- · Notebook Computers
- · Network Interface Cards
- Palmtop Computers
- · 2.5V to 1.XV Regulators

Description

The MCP1824/MCP1824S is a 300 mA Low Dropout (LDO) linear regulator that provides high current and low output voltages. The MCP1824 comes in a fixed or adjustable output voltage version, with an output voltage range of 0.8V to 5.0V. The 300 mA output current capability, combined with the low output voltage capability, make the MCP1824 a good choice for new sub-1.8V output voltage LDO applications that have high current demands. The MCP1824S is a 3-pin fixed voltage version.

The MCP1824/MCP1824S is stable using ceramic output capacitors that inherently provide lower output noise and reduce the size and cost of the entire regulator solution. Only 1 μF of output capacitance is needed to stabilize the LDO.

Using CMOS construction, the quiescent current consumed by the MCP1824/MCP1824S is typically less than 120 μA over the entire input voltage range, making it attractive for portable computing applications that demand high output current. The MCP1824 versions have a Shutdown (\overline{SHDN}) pin. When shut down, the quiescent current is reduced to less than 0.1 μA .

On the MCP1824 fixed output versions, the scaled-down output voltage is internally monitored and a power good (PWRGD) output is provided when the output is within 92% of regulation (typical). The PWRGD delay is internally fixed at 110 µs (typical).

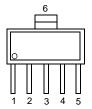
The overtemperature and short circuit current-limiting provide additional protection for the LDO during system fault conditions.

Package Types







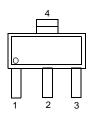




	SOT	-223	SOT-23		
Pin	Fixed	Fixed Adjustable		Adjustable	
1	SHDN	SHDN	V _{IN}	V _{IN}	
2	V _{IN}	V_{IN}	GND (TAB)	GND (TAB)	
3	GND (TAB)	GND (TAB)	SHDN	SHDN	
4	V _{OUT}	V _{OUT}	PWRGD	ADJ	
5	PWRGD	ADJ	V _{OUT}	V _{OUT}	
6	GND (TAB)	GND (TAB)	_	_	

MCP1824S

SOT-223-3



Pin	SOT-223
1	V _{IN}
2	GND (TAB)
3	V _{OUT}
4	GND (TAB)

1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings †

 $\label{eq:local_$

† Notice: Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

AC/DC CHARACTERISTICS

Electrical Specifications: Unless otherwise noted, $V_{IN} = V_{OUT(MAX)} + V_{DROPOUT(MAX)}$, **Note 1**, $V_{R} = 1.8V$ for Adjustable Output, $I_{OUT} = 1$ mA, $C_{IN} = C_{OUT} = 4.7 \ \mu F$ (X7R Ceramic), $T_{A} = +25^{\circ}C$. **Boldface** type applies for junction temperatures, T_{I} (**Note 7**) of **-40°C to +125°C**

Parameters	Sym	Min	Тур	Max	Units	Conditions	
Input Operating Voltage	V _{IN}	2.1	_	6.0	V		
Output Voltage Range	V _{OUT}	0.8	_	5.0	V		
Input Quiescent Current	Iq	_	120	220	μА	$I_L = 0 \text{ mA}, V_{OUT} = 0.8 \text{V to}$ 5.0 V	
Input Quiescent Current for SHDN Mode	I _{SHDN}	_	0.1	3	μА	SHDN = GND	
Maximum Continuous Output Current	I _{OUT}	300	_	_	mA	V _{IN} = 2.1V to 6.0V V _R = 0.8V to 5.0V	
Line Regulation	$\Delta V_{OUT} / (V_{OUT} \times \Delta V_{IN})$	_	±0.05	±0. 17	%/V	(Note 1) \leq $V_{IN} \leq$ 6 V	
Load Regulation	ΔV _{OUT} /V _{OUT}	-1.0	±0.5	1.0	%	I _{OUT} = 1 mA to 300 mA, (Note 4)	
Output Short Circuit Current	I _{OUT_SC}	_	720	_	mA	$R_{LOAD} < 0.1\Omega$, Peak Current	
Dropout Voltage	V _{DROPOUT}	_	200	320	mV	Note 5, I _{OUT} = 300 mA, V _{IN(MIN)} = 2.1V	
Pulsed Applications							
Maximum Pulsed Output Current	I _{PULSE}	_	500	_	mA	$\begin{aligned} &V_{\text{IN}} = 2.1 \text{V to } 6.0 \text{V} \\ &V_{\text{R}} = 0.8 \text{V to } 5.0 \text{V}, \\ &\text{Duty Cycle} \leq 60\%, \\ &\text{Period} < 10 \text{ ms} \end{aligned}$	

- Note 1: The minimum V_{IN} must meet two conditions: $V_{IN} \ge 2.1 V$ and $V_{IN} \ge V_{OUT(MAX)} + V_{DROPOUT(MAX)}$.
 - 2: V_R is the nominal regulator output voltage for the fixed cases. $V_R = 1.2V$, 1.8V, etc. V_R is the desired set point output voltage for the adjustable cases. $V_R = V_{ADJ} * ((R_1/R_2)+1)$. Figure 4-1.
 - 3: TCV_{OUT} = (V_{OUT-HIGH} V_{OUT-LOW}) *10⁶ / (V_R * ΔTemperature). V_{OUT-HIGH} is the highest voltage measured over the temperature range. V_{OUT-LOW} is the lowest voltage measured over the temperature range.
 - **4:** Load regulation is measured at a constant junction temperature using low duty-cycle pulse testing. Load regulation is tested over a load range from 1 mA to the maximum specified output current.
 - 5: Dropout voltage is defined as the input-to-output voltage differential at which the output voltage drops 2% below its nominal value that was measured with an input voltage of V_{IN} = V_{OUT(MAX)} + V_{DROPOUT(MAX)}.
 - 6: The maximum allowable power dissipation is a function of ambient temperature, the maximum allowable junction temperature and the thermal resistance from junction to air. (i.e., T_A, T_J, θ_{JA}). Exceeding the maximum allowable power dissipation will cause the device operating junction temperature to exceed the maximum +150°C rating. Sustained junction temperatures above 150°C can impact device reliability.
 - 7: The junction temperature is approximated by soaking the device under test at an ambient temperature equal to the desired junction temperature. The test time is small enough such that the rise in the junction temperature over the ambient temperature is not significant.

AC/DC CHARACTERISTICS (CONTINUED)

 $\textbf{Electrical Specifications:} \ \ \textbf{Unless otherwise noted}, \ \ \textbf{V}_{IN} = \textbf{V}_{OUT(MAX)} + \textbf{V}_{DROPOUT(MAX)}, \ \textbf{Note 1}, \ \textbf{V}_{R} = \textbf{1.8V} \ \ \text{for Adjustable Output},$ $I_{OUT} = 1$ mA, $C_{IN} = C_{OUT} = 4.7 \mu F$ (X7R Ceramic), $T_A = +25$ °C.

Boldface type applies for junction temperatures, T_J (Note 7) of -40°C to +125°C

Parameters	Sym	Min	Тур	Max	Units	Conditions
Maximum Pulsed Output Duty Cycle	I _{PULSE_DUTY}	_	_	60	%	$V_{IN} = 2.1 V \text{ to } 6.0 V,$ $V_R = 0.8 V \text{ to } 5.0 V,$ $I_{OUT} = 500 \text{ mA},$ Period < 10 ms
Maximum Pulsed Output Period	I _{PULSE_PERIOD}	_	_	10	ms	$V_{IN} = 2.1V \text{ to } 6.0V$ $V_R = 0.8V \text{ to } 5.0V,$ $I_{OUT} = 500 \text{ mA}$
Adjust Pin Characteristics (Adj	ustable Output O	nly)				
Adjustable Output Voltage Range	V_{OUT_ADJ}	0.8	_	5.5	V	
Adjust Pin Reference Voltage	V_{ADJ}	0.402	0.410	0.418	V	$V_{IN} = 2.1 V$ to $V_{IN} = 6.0 V$, $I_{OUT} = 1$ mA
Adjust Pin Leakage Current	I _{ADJ}	-10	±0.01	+10	nA	$V_{IN} = 6.0V, V_{ADJ} = 0V \text{ to } 6V$
Adjust Temperature Coefficient	TCV _{OUT}	_	40	_	ppm/°C	Note 3
Fixed-Output Characteristics (F	ixed Output Only)				
Voltage Regulation	V _{OUT}	V _R - 2.5%	V _R ±0.5%	V _R + 2.5%	V	Note 2
Power Good Characteristics						
PWRGD Input Voltage Operat-	V _{PWRGD_VIN}	1.0	_	6.0	V	T _A = +25°C
ing Range		1.2	_	6.0		$T_A = -40^{\circ}C \text{ to } +125^{\circ}C$
						For V_{IN} < 2.1V, I_{SINK} = 100 μ A
PWRGD Threshold Voltage	V_{PWRGD_TH}				%V _{OUT}	Falling Edge
(Referenced to V _{OUT})		89	92	95		V _{OUT} < 2.5V Fixed, V _{OUT} = Adj.
		90	92	94		V _{OUT} >= 2.5V Fixed
PWRGD Threshold Hysteresis	V _{PWRGD_HYS}	1.0	2.0	3.0	%V _{OUT}	
PWRGD Output Voltage Low	V_{PWRGD_L}	_	0.05	0.4	V	I _{PWRGD SINK} = 1.2 mA, ADJ = 0V
PWRGD Output Current Sink Capability	I _{PWRGD}	1.2	6.0	_	mA	V _{PWRGD} = 0.200V
PWRGD Leakage	P _{WRGD-LK}		1		nA	$V_{PWRGD} = V_{IN} = 6.0V$
PWRGD Time Delay	T _{PG}	_	110	_	μs	Rising Edge $R_{PULLUP} = 10 \text{ k}\Omega$

- The minimum V_{IN} must meet two conditions: $V_{IN} \ge 2.1V$ and $V_{IN} \ge V_{OUT(MAX)} + V_{DROPOUT(MAX)}$. Note
 - V_R is the nominal regulator output voltage for the fixed cases. V_R = 1.2V, 1.8V, etc. V_R is the desired set point output
 - voltage for the adjustable cases. $V_R = V_{ADJ} * ((R_1/R_2)+1)$. Figure 4-1. $TCV_{OUT} = (V_{OUT-HIGH} V_{OUT-LOW}) *10^6 / (V_R * \Delta Temperature)$. $V_{OUT-HIGH}$ is the highest voltage measured over the temperature range. $V_{\mbox{\scriptsize OUT-LOW}}$ is the lowest voltage measured over the temperature range.
 - Load regulation is measured at a constant junction temperature using low duty-cycle pulse testing. Load regulation is tested over a load range from 1 mA to the maximum specified output current.
 - Dropout voltage is defined as the input-to-output voltage differential at which the output voltage drops 2% below its nominal value that was measured with an input voltage of V_{IN} = V_{OUT(MAX)} + V_{DROPOUT(MAX)}.
 - The maximum allowable power dissipation is a function of ambient temperature, the maximum allowable junction temperature and the thermal resistance from junction to air. (i.e., T_A , T_J , θ_{JA}). Exceeding the maximum allowable power dissipation will cause the device operating junction temperature to exceed the maximum +150°C rating. Sustained junction temperatures above 150°C can impact device reliability.
 - The junction temperature is approximated by soaking the device under test at an ambient temperature equal to the desired junction temperature. The test time is small enough such that the rise in the junction temperature over the ambient temperature is not significant.

AC/DC CHARACTERISTICS (CONTINUED)

Electrical Specifications: Unless otherwise noted, $V_{IN} = V_{OUT(MAX)} + V_{DROPOUT(MAX)}$, Note 1, $V_{R} = 1.8V$ for Adjustable Output, $I_{OUT} = 1$ mA, $C_{IN} = C_{OUT} = 4.7 \ \mu F$ (X7R Ceramic), $T_{A} = +25^{\circ}C$.

Boldface type applies for junction temperatures, T_J (Note 7) of -40°C to +125°C

Parameters	Sym	Min	Тур	Max	Units	Conditions		
Detect Threshold to PWRGD T _{VDET-PWRGD} Active Time Delay		_	200	_	μs	$V_{OUT} = V_{PWRGD_TH} + 50 \text{ mV}$ to $V_{PWRGD_TH} - 50 \text{ mV}$		
Shutdown Input								
Logic High Input	V _{SHDN-HIGH}	45	_	1	%V _{IN}	V _{IN} = 2.1V to 6.0V		
Logic Low Input	V _{SHDN-LOW}	_	_	15	%V _{IN}	V _{IN} = 2.1V to 6.0V		
SHDN Input Leakage Current SHDN _{ILK}		-0.1	±0.001	+0.1	μA	$\frac{V_{IN} = 6V, \overline{SHDN} = V_{IN},}{\overline{SHDN} = GND}$		
AC Performance			•					
Output Delay From SHDN	T _{OR}	_	100	_	μs	$\overline{SHDN} = GND \text{ to } V_{IN},$ $V_{OUT} = GND \text{ to } 95\% \text{ V}_{R}$		
Output Noise	e _N	_	2.0		μV/√Hz	$\begin{split} I_{OUT} &= 200 \text{ mA, f} = 1 \text{ kHz,} \\ C_{OUT} &= 10 \mu\text{F (X7R Ceramic),} \\ V_{OUT} &= 2.5 \text{V} \end{split}$		
Power Supply Ripple Rejection Ratio	PSRR	_	55	1	dB	$\begin{split} f &= 100 \text{ Hz}, \\ I_{OUT} &= 10 \text{ mA}, \\ V_{INAC} &= 200 \text{ mV pk-pk}, \\ C_{IN} &= 0 \mu\text{F} \end{split}$		
Thermal Shutdown Temperature	T _{SD}	_	150		°C	I _{OUT} = 100 μA, V _{OUT} = 1.8V, V _{IN} = 2.8V		
Thermal Shutdown Hysteresis	$\Delta T_{\sf SD}$	_	10	_	°C	$I_{OUT} = 100 \mu A, V_{OUT} = 1.8V,$ $V_{IN} = 2.8V$		

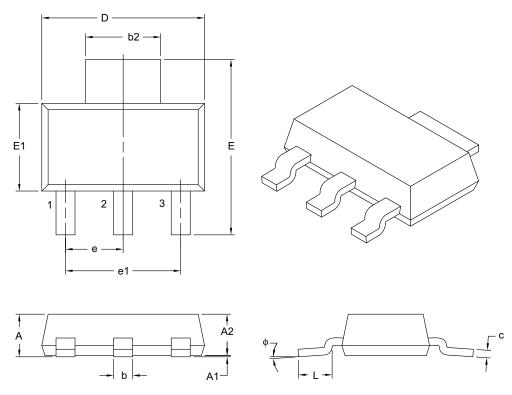
Note 1: The minimum V_{IN} must meet two conditions: $V_{IN} \ge 2.1 V$ and $V_{IN} \ge V_{OUT(MAX)} + V_{DROPOUT(MAX)}$.

- 2: V_R is the nominal regulator output voltage for the fixed cases. $V_R = 1.2V$, 1.8V, etc. V_R is the desired set point output voltage for the adjustable cases. $V_R = V_{ADJ} \cdot ((R_1/R_2)+1)$. Figure 4-1.
- 3: $TCV_{OUT} = (V_{OUT-HIGH} V_{OUT-LOW}) *10^6 / (V_R * \Delta Temperature)$. $V_{OUT-HIGH}$ is the highest voltage measured over the temperature range. $V_{OUT-LOW}$ is the lowest voltage measured over the temperature range.
- 4: Load regulation is measured at a constant junction temperature using low duty-cycle pulse testing. Load regulation is tested over a load range from 1 mA to the maximum specified output current.
- 5: Dropout voltage is defined as the input-to-output voltage differential at which the output voltage drops 2% below its nominal value that was measured with an input voltage of V_{IN} = V_{OUT(MAX)} + V_{DROPOUT(MAX)}.
- 6: The maximum allowable power dissipation is a function of ambient temperature, the maximum allowable junction temperature and the thermal resistance from junction to air. (i.e., T_A, T_J, θ_{JA}). Exceeding the maximum allowable power dissipation will cause the device operating junction temperature to exceed the maximum +150°C rating. Sustained junction temperatures above 150°C can impact device reliability.
- 7: The junction temperature is approximated by soaking the device under test at an ambient temperature equal to the desired junction temperature. The test time is small enough such that the rise in the junction temperature over the ambient temperature is not significant.

TEMPERATURE SPECIFICATIONS

Parameters	Sym	Min	Тур	Max	Units	Conditions	
Temperature Ranges							
Operating Junction Temperature Range	T_J	-40	_	+125	°C	Steady State	
Maximum Junction Temperature	T_J	_	_	+150	°C	Transient	
Storage Temperature Range	T _A	-65	_	+150	°C		
Thermal Package Resistances							
Thermal Resistance, 3LD SOT-223	θ_{JA}	_	62	_	°C/W	EIA/JEDEC JESD51-751-7	
	θ_{JC}	_	15	_		4 Layer Board	
Thermal Resistance, 5LD SOT-23	θ_{JA}	_	256	_	°C/W	EIA/JEDEC JESD51-751-7 4 Layer Board	
	θ_{JC}	_	81	_			
Thermal Resistance, 5LD SOT-223	θ_{JA}	_	62	_	°C/W	EIA/JEDEC JESD51-751-	
	θ_{JC}	_	15	_		4 Layer Board	

3-Lead Plastic Small Outline Transistor (DB) [SOT-223]



	Unit	ts		MILLIMETERS	3	
	Dimension Limits		MIN	NOM	MAX	
Number of Leads	umber of Leads N			3		
Lead Pitch	е		2.30 BSC			
Outside Lead Pitch	e1			4.60 BSC		
Overall Height	A		_	_	1.80	
Standoff	A1		0.02	_	0.10	
Molded Package Height	A2		1.50	1.60	1.70	
Overall Width	E		6.70	7.00	7.30	
Molded Package Width	E1		3.30	3.50	3.70	
Overall Length	D		6.30	6.50	6.70	
Lead Thickness	С		0.23	0.30	0.35	
Lead Width	b		0.60	0.76	0.84	
Tab Lead Width	b2		2.90	3.00	3.10	
Foot Length	L		0.75	_	_	
Lead Angle	ф		0°	_	10°	

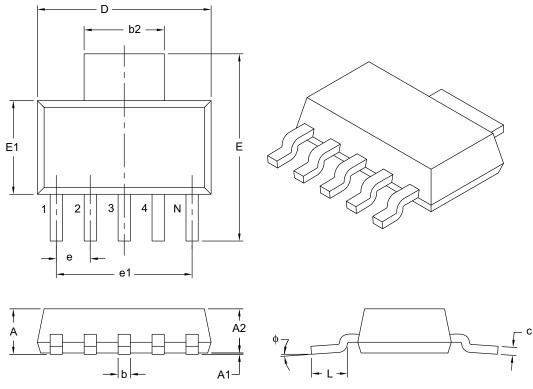
Notes:

- 1. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.127 mm per side.
- 2. Dimensioning and tolerancing per ASME Y14.5M.

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-032B

5-Lead Plastic Small Outline Transistor (DC) [SOT-223]



	Units		MILLIMETERS	3	
Dimens	Dimension Limits		NOM	MAX	
Number of Leads	mber of Leads N		5		
Lead Pitch	е	1.27 BSC			
Outside Lead Pitch	e1		5.08 BSC		
Overall Height	А	1.80			
Standoff	A1	0.02	0.06	0.10	
Molded Package Height	A2	1.55	1.60	1.65	
Overall Width	E	6.86	7.00	7.26	
Molded Package Width	E1	3.45	3.50	3.55	
Overall Length	D	6.45	6.50	6.55	
Lead Thickness	С	0.24	0.28	0.32	
Lead Width	b	0.41	0.457	0.51	
Tab Lead Width	b2	2.95	3.00	3.05	
Foot Length	L	0.91	_	1.14	
Lead Angle	ф	0°	4°	8°	

Notes:

- 1. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.127 mm per side.
- 2. Dimensioning and tolerancing per ASME Y14.5M.

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-137B

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

PART NO. XX	<u> </u>	Examples:
Device Output Voltage		a) MCP1824-0802E/XX: 0.8V LDO Regulator b) MCP1824-1002E/XX: 1.0V LDO Regulator c) MCP1824-1202E/XX: 1.2V LDO Regulator d) MCP1824-1802E/XX: 1.8V LDO Regulator
Device:	MCP1824: 300 mA Low Dropout Regulator MCP1824T: 300 mA Low Dropout Regulator Tape and Reel MCP1824S: 300 mA Low Dropout Regulator MCP1824ST: 300 mA Low Dropout Regulator Tape and Reel	e) MCP1824-2502E/XX: 2.5V LDO Regulator f) MCP1824-3002E/XX: 3.0V LDO Regulator g) MCP1824-3302E/XX: 3.3V LDO Regulator h) MCP1824-5002E/XX: 5.0V LDO Regulator i) MCP1824-ADJE/XX: ADJ LDO Regulator
Output Voltage *:	08 = 0.8V "Standard" 12 = 1.2V "Standard" 18 = 1.8V "Standard" 25 = 2.5V "Standard" 30 = 3.0V "Standard" 31 = 3.3V "Standard" 50 = 5.0V "Standard" 60 = 5.0V "Standard" 70 = 7.0V	a) MCP1824S-0802E/XX:0.8V LDO Regulator b) MCP1824S-1002E/XX:1.0V LDO Regulator c) MCP1824S-1202E/XX:1.2V LDO Regulator d) MCP1824S-1802E/XX:1.8V LDO Regulator e) MCP1824S-2502E/XX:2.5V LDO Regulator f) MCP1824S-2502E/XX:3.0V LDO Regulator g) MCP1824S-3302E/XX:3.3V LDO Regulator h) MCP1824S-5002E/XX:5.0V LDO Regulator
Extra Feature Code:	"tolerance" columns do not apply. Refer to examples. 0 = Fixed	XX = DB for 3LD SOT-223 package
Tolerance:	2 = 2.5% (Standard)	= DC for 5LD SOT-223 package = OT for 5LD SOT-23 package
Temperature:	E = -40°C to +125°C	
Package Type:	DB = Plastic Small Transistor Outline, SOT-223, 3-lead DC = Plastic Small Transistor Outline, SOT-223, 5-lead OT = Plastic Small Transistor Outline, SOT-23, 5-lead	
	Note: ADJ (Adjustable) only available in 5-lead version.	